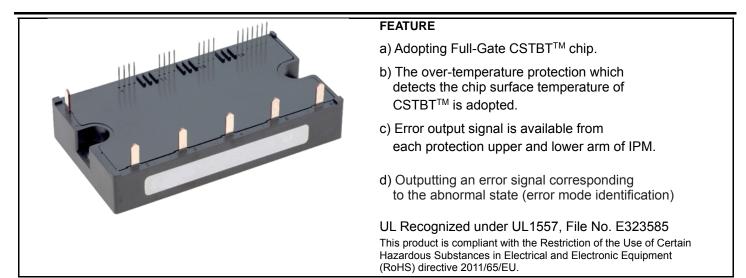


<Intelligent Power Modules>

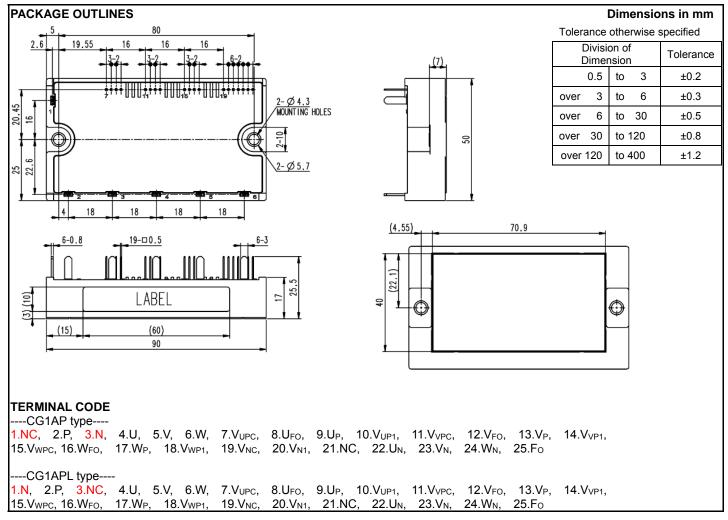
# PM50CG1AP065/PM50CG1APL065

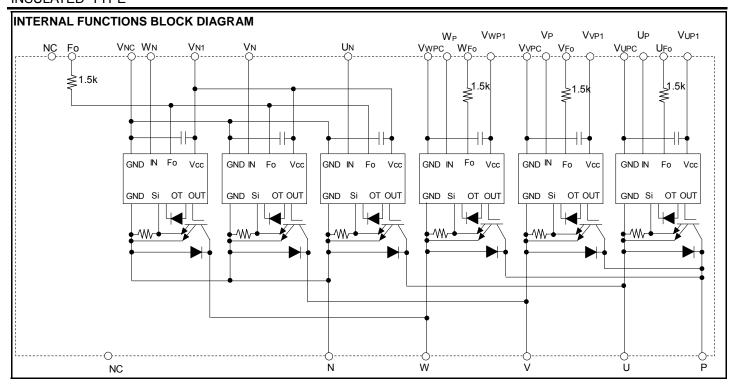
FLAT-BASE TYPE INSULATED PACKAGE



## APPLICATION

General purpose inverter, servo drives and other motor controls





MAXIMUM RATINGS (Tvj = 25°C, unless otherwise noted)

#### **INVERTER PART**

Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CES</sub>	Collector-Emitter Voltage	V <sub>D</sub> =15 V, V <sub>CIN</sub> =15 V	650	V
I <sub>C</sub>		T <sub>c</sub> =25 °C	50	^
I <sub>CRM</sub>	Collector Current	Pulse	100	A
P <sub>tot</sub>	Total Power Dissipation	T <sub>c</sub> =25 °C	240	W
l <sub>E</sub>	Emitter Current	T <sub>c</sub> =25 °C	50	^
I <sub>ERM</sub>	(Free-wheeling Diode Forward current)	Pulse	100	A
Tvj	Junction Temperature		-20 ~ +150	°C

\*: Tc measurement point is just under the chip.

#### **CONTROL PART**

Symbol	Parameter	Conditions	Ratings	Unit
VD	Supply Voltage	Applied between: $V_{UP1}$ - $V_{UPC}$ , $V_{VP1}$ - $V_{VPC}$ , $V_{WP1}$ - $V_{WPC}$ , $V_{N1}$ - $V_{NC}$	20	V
V <sub>CIN</sub>	Input Voltage	Applied between: $U_P-V_{UPC}$ , $V_P-V_{VPC}$ , $W_P-V_{WPC}$ , $U_N$ , $V_N$ , $W_N-V_{NC}$	20	V
V <sub>FO</sub>	Fault Output Supply Voltage	Applied between: $U_{FO}$ - $V_{UPC}$ , $V_{FO}$ - $V_{VPC}$ , $W_{FO}$ - $V_{WPC}$ , FO- $V_{NC}$	20	V
I <sub>FO</sub>	Fault Output Current	Sink current at $U_{FO}$ , $V_{FO}$ , $W_{FO}$ , Fo terminals	20	mA

#### TOTAL SYSTEM

Symbol	Parameter	Conditions	Ratings	Unit
V <sub>CC(PROT)</sub>	Supply Voltage Protected by SC	V <sub>D</sub> =13.5 V∼16.5 V, Inverter Part, Tvj=+125°C start	400	V
T <sub>stg</sub>	Storage Temperature	-	-40 ~ +125	°C
Tc	Operating Case Temperature	-	-20 ~ +125	°C
Visol	Isolation Voltage	60Hz, Sinusoidal, Charged part to Base plate, AC 1min, RMS	2500	V

\*: Tc measurement point is just under the chip.

### THERMAL RESISTANCE

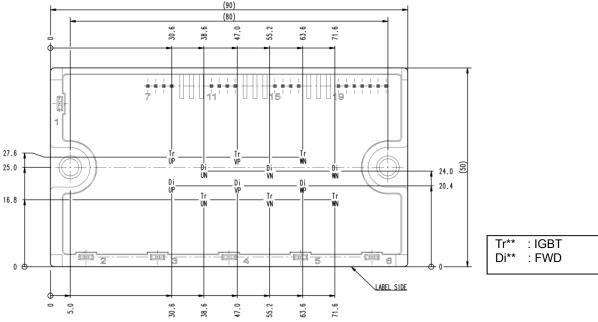
Symbol	Parameter	Conditions	Limits			Linit
		Conditions		Тур.	Max.	Unit
R <sub>th(j-c)Q</sub>	Thermal Resistance	Junction to case, IGBT, per 1 element (Note1)	-	-	0.52	κ/w
$R_{th(j-c)D}$		Junction to case, FWD, per 1 element (Note1)	-	-	0.88	
$R_{th(c\text{-}s)}$	Contact Thermal Resistance	Case to heat sink, per 1 module,	_	19.1 -	K/kW	
		Thermal grease applied (Note.1, 2)				10100

Note1. If you use this value,  $R_{\text{th}(s\text{-}a)}$  should be measured just under the chips.

Note2. Typical value is measured by using thermally conductive grease of  $\lambda$ =0.9W/(m·K), D<sub>(C-S)</sub>=50 µm.

#### CHIP LOCATION (Top view)

Dimension in mm, torelance: ±1mm



**ELECTRICAL CHARACTERISTICS** (Tvj= 25°C, unless otherwise noted) **INVERTER PART** 

Symbol	Parameter	Conditions		Conditions		Limits		Unit
Symbol	Falanelei	Conditions			Min.	Тур.	Max.	Unit
		V <sub>D</sub> =15 V, I <sub>C</sub> =50 A Tvj=25 °C	Terminal	-	-	1.7		
V	Collector-Emitter Saturation Voltage		TVJ=25 C	Chip	-	1.25	-	v
V <sub>CEsat</sub>	•	(-0)/ Dulaced (Fig. 1)	Tui-105 °C	Terminal	-	-	1.95	v
		V <sub>CIN</sub> =0 V, Pulsed, (Fig.1)	Tvj=125 °C	Chip	-	1.33	-	
	Emitter-Collector Voltage	V <sub>D</sub> =15 V, I <sub>E</sub> =50 A, Tvj=25 °C	Tui=25 °C	Terminal	-	-	1.9	V
V <sub>EC</sub>			10]-25 C	Chip	-	1.40	-	
V EC		V <sub>CIN</sub> = 15 V, pulsed, (Fig.2) Tvj=125 °C	Tui=125 °C	Terminal	-	-	2.0	
			TVJ=125 C	Chip	-	1.45	-	
t <sub>on</sub>		$V_D=15 V, V_{CIN}=0 V \leftrightarrow 15 V,$ $V_{CC}=300 V, I_C=50A,$ Tvj=125 °C, Inductive Load (Fig.3, 4)		0.3	0.6	1.2		
t <sub>rr</sub>				-	0.2	0.65		
t <sub>c(on)</sub>	Switching Time				-	0.17	0.75	μs
t <sub>off</sub>				-	1.0	2.3	1	
t <sub>c(off)</sub>					-	0.13	0.4	
1		V <sub>CE</sub> =V <sub>CES</sub> , V <sub>D</sub> =15 V,		Tvj=25 °C	-	-	1	
I <sub>CES</sub>	Collector-Emitter Cut-off Current	Current V -45 V (Fire 5)	Tvj=125 °C	-	-	10	mA	

#### ELECTRICAL CHARACTERISTICS (Tvj = 25°C, unless otherwise noted)

#### CONTROL PART

Symbol	Deremeter	Conditions	Conditions		Limits			
Symbol	Parameter	Conditions		Min.	Тур.	Max.	Unit	
			V <sub>P1</sub> -V <sub>PC</sub>	-	4	6		
1	Circuit Current	V <sub>D</sub> =15 V, V <sub>CIN</sub> =15 V	V <sub>N1</sub> -V <sub>NC</sub>	-	12	18	mA	
ID		$V_{D}$ =15 V, $V_{CIN}$ =0 V $\leftrightarrow$ 15 V, $V_{CC}$ =400 V	$V_{P1}$ - $V_{PC}$	-	10	12	mA	
		I <sub>C</sub> =0A, Tvj=125 °C, f <sub>C</sub> ≤20kHz	V <sub>N1</sub> -V <sub>NC</sub>	-	29	35	]	
V <sub>th(ON)</sub>	Input ON Threshold Voltage	Applied between:		1.2	1.5	1.8	v	
$V_{th(OFF)}$	Input OFF Threshold Voltage	$U_{P}$ - $V_{UPC}$ , $V_{P}$ - $V_{VPC}$ , $W_{P}$ - $V_{WPC}$ , $U_{N}$ , $V_{N}$ , $W_{N}$ - $V_{NC}$		1.7	2.0	2.3	v	
SC	Short Circuit Trip Level	-20≤Tvj≤125 °C, V <sub>D</sub> =15 V (Fig.3, 6)		100	-	-	А	
t <sub>d(SC)</sub>	Short Circuit Current Delay Time	V <sub>D</sub> =15 V, Tvj=125 °C (Fig.3, 6)		-	2.0	-	μs	
ОТ	Quer Temperature Protection	er Temperature Protection Detect temperature of IGBT chip surface	Trip level	150	-	-	<b>.</b>	
OT <sub>(hys)</sub>			Hysteresis	-	20	-		
UVt	Supply Circuit		Trip level	11.0	12.0	12.7	v	
UVr	Under-Voltage Protection	-	Reset level	-	12.5	-		
I <sub>FO(H)</sub>	Foult Output Current	(1 - 15)(1) - 15(1)(1)(1 - 15)		-	-	0.01	mA	
I <sub>FO(L)</sub>	Fault Output Current	$V_{D}$ =15 V, $V_{FO}$ =15 V (Note3)		-	10	15	mA	
		V <sub>D</sub> =15 V (Note3)	ОТ	-	8.0	-		
t <sub>FO</sub>	Fault Output Pulse Width		UV	-	4.0	-	ms	
			SC	-	2.0	-		

Note3. Fault output is given only when the internal SC, OT & UV protections schemes of either upper or lower arm device operate to protect it.

#### MECHANICAL RATINGS AND CHARACTERISTICS

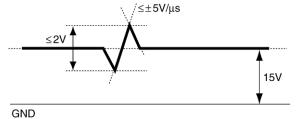
Symbol	Parameter	Conditions		Limits		
Symbol				Тур.	Max.	Unit
Ms	Mounting Torque	Mounting part screw : M4	1.5	1.7	2.0	N•m
m	mass	-	-	175	-	g

#### **RECOMMENDED CONDITIONS FOR USE**

Symbol	Parameter	Conditions	Recommended value	Unit
Vcc	Supply Voltage	Applied across P-N terminals	≤ 400	V
V <sub>D</sub>	Control Supply Voltage	Applied between : V <sub>UP1</sub> -V <sub>UPC</sub> , V <sub>VP1</sub> -V <sub>VPC</sub> , V <sub>WP1</sub> -V <sub>WPC</sub> ,V <sub>N1</sub> -V <sub>NC</sub> (Note4)	15.0±1.5	V
V <sub>CIN(ON)</sub>	Input ON Voltage	Applied between :	≤ 0.8	v
$V_{CIN(OFF)}$	Input OFF Voltage	$U_P\text{-}V_UPC,V_P\text{-}V_VPC,W_P\text{-}V_WPC,U_N,V_N,W_N\text{-}V_NC$	≥ 9.0	v
f <sub>PWM</sub>	PWM Input Frequency	Using Application Circuit of Fig. 8	≤ 20	kHz
t <sub>dead</sub>	Arm Shoot-through Blocking Time	For IPM's each input signals (Fig.7)	≥ 2.0	μs

This product is compliant with the Restriction of the Use of Certain Hazardous Substances in Electrical and Electronic Equipment (RoHS) directive 2011/65/EU.

Note4. With ripple satisfying the following conditions: dv/dt swing ≤ ±5 V/µs, Variation ≤ 2 V peak to peak



**INSULATED TYPE** 

## **PRECAUTIONS FOR TESTING**

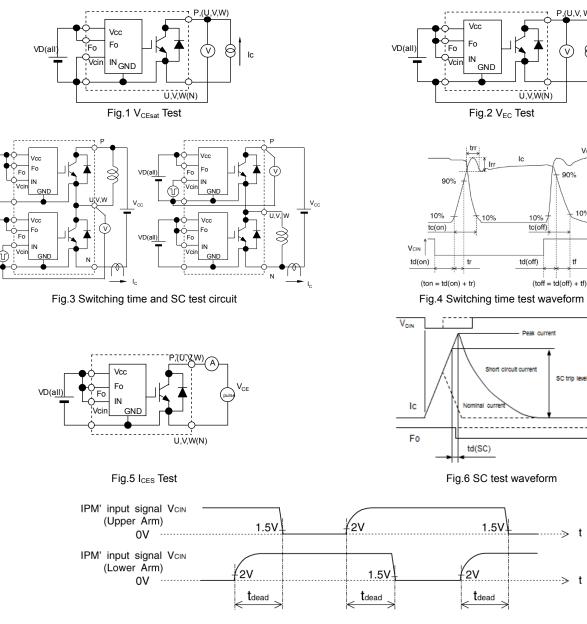
VD(all

1. Before applying any control supply voltage (V<sub>D</sub>), the input terminals should be pulled up by resistors, etc. to their corresponding supply voltage and each input signal should be kept off state.

After this, the specified ON and OFF level setting for each input signal should be done.

2. When performing "SC" tests, the turn-off surge voltage spike at the corresponding protection operation should not be allowed to rise above VCES rating of the device.

(These test should not be done by using a curve tracer or its equivalent.)



1.5V: Input on threshold voltage Vth(on) typical value, 2V: Input off threshold voltage Vth(off) typical value Fig. 7 Dead time measurement point example

P.(U.V.W)

VCE

10%

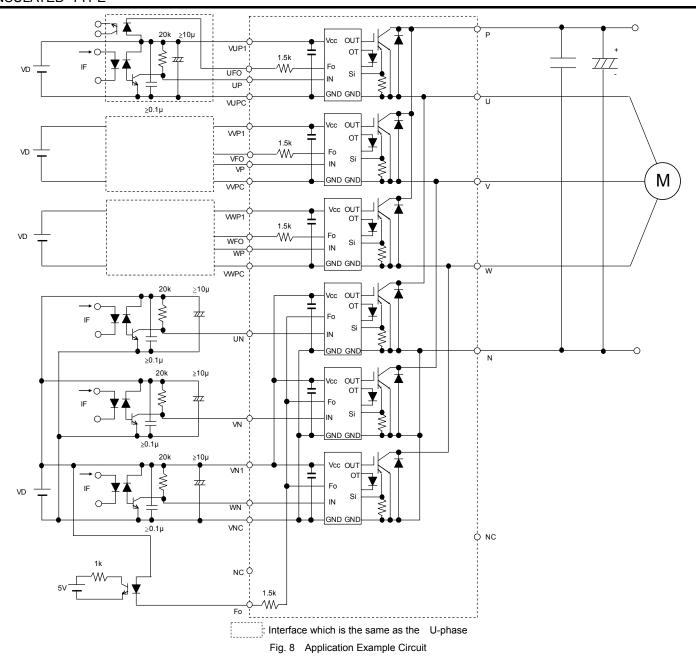
tf

SC trip le

t

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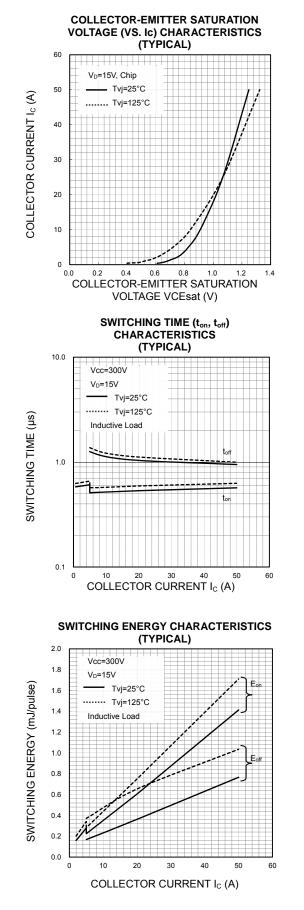
90%

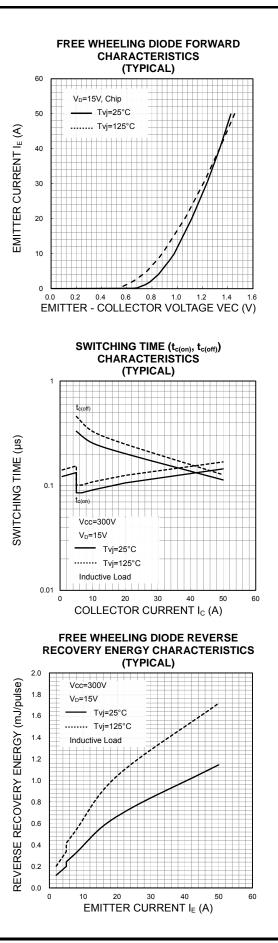


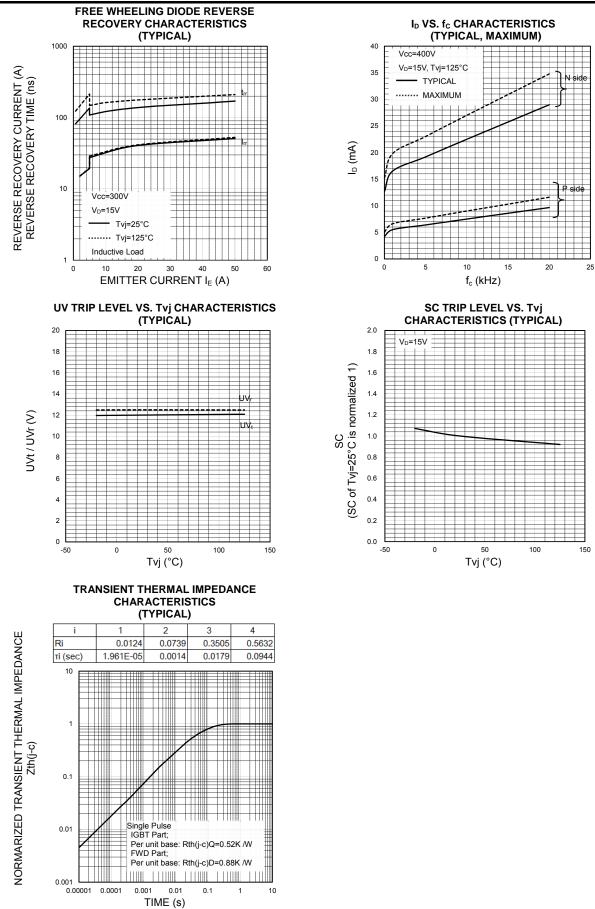
#### NOTES FOR STABLE AND SAFE OPERATION ;

- Design the PCB pattern to minimize wiring length between opto-coupler and IPM's input terminal, and also to minimize the stray capacity between the input and output wirings of opto-coupler.
- Connect low impedance capacitor between the Vcc and GND terminal of each fast switching opto-coupler.
- Fast switching opto-couplers:  $t_{PLH}$ ,  $t_{PHL} \le 0.8 \mu s$ , Use High CMR type.
- Slow switching opto-coupler: CTR > 100%
- Use 4 isolated control power supplies (V<sub>D</sub>). Also, care should be taken to minimize the instantaneous voltage charge of the power supply.
- Make inductance of DC bus line as small as possible, and minimize surge voltage using snubber capacitor between P and N terminal.

#### **PERFORMANCE CURVES**







## Keep safety first in your circuit designs!

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